## Solution to Exercise 2.3.5-1

We want to show that the following two equations are equivalent for equilibrium:

$$n_{e}^{p}(U) \begin{vmatrix} SCR &= n_{e}^{n}(U) \\ edge \end{vmatrix} \begin{vmatrix} SCR &\cdot exp &-\frac{e(V^{n} + U)}{kT} \end{vmatrix}$$
$$n_{e}^{p}(U=0) = \frac{n_{l}^{2}}{n_{h}^{p}(U=0)}$$

The first equation then simplifies to

$$n_{e}^{p}(U) \begin{vmatrix} SCR = n_{e}^{n}(U) \\ edge \end{vmatrix} \begin{vmatrix} SCR \cdot exp - \frac{eV^{n}}{kT} \\ edge \end{vmatrix} = n_{e}^{n}(U) \begin{vmatrix} SCR \cdot exp - \frac{\Delta E_{F}}{kT} \\ edge \end{vmatrix} = kT$$

Start with the equation for the majority carrier concentration  $n_h^p(U=0)$  in general and the definitions of the energies:

$$n_{h}{}^{p}(U=0) = N_{eff}{}^{p} \cdot exp - \frac{E_{F} - E_{V}{}^{p}}{kT}$$
  
e.  $V^{n} = \frac{\text{Difference of}}{\text{band edges}} = E_{V}{}^{p} - E_{V}{}^{n} = E_{C}{}^{p} - E_{C}{}^{n} = \triangle E_{F}$ 

Consult the solution to the <u>Poisson equation</u> if you are unsure (the relevant diagram is reprinted below) and recall that in the band diagram, the energy scale refers to electrons, which carry a negative electric charge – so that the electrostatic potential contributes with a negative sign.

Also note that *E<sub>F</sub>*, of course, is constant in equilibrium, and *A<sub>E<sub>F</sub>* thus refers to the difference in Fermi energies before the contact !</sub>



**F**  $E_V^p$  thus can be expressed as  $E_V^p = E_V^n + \Delta E_F$ .

- This brings you already to the n-side. However, you want to find nen in the equation, and for that you need a factor Ecn EF.
- So, express  $E_V n$  in terms of  $E_C n$  via  $E_V n = E_C n E_g$  with  $E_g$  = band gap. This yields

$$n_{\rm h}{}^{\rm p}(U=0) = N_{\rm eff}{}^{\rm p} \cdot \exp{-rac{E_{\rm F}-E_{\rm C}{}^{\rm n}+E_{\rm g}-\Delta E_{\rm F}}{kT}}$$

You now have terms that occur in the definition of the electron density in **n-Si** [namely,  $E_F - E_C^n = -(E_C^n - E_F)$ ] and for the intrinsic carrier density (namely,  $E_g$ ).

So, multiply with  $N_{eff} ^{n} / N_{eff} ^{n}$ , remember that  $n_{i}^{2} = N_{eff} \cdot N_{eff} \cdot exp - E_{g}/(kT)$ , and  $1/n_{e}^{n} = 1/N_{eff}^{n} \cdot exp[(E_{C}^{n} - E_{F})/(k_{T})]$ ; thus, you have

$$n_{\rm h}^{\rm p}(U=0) = \frac{n_{\rm l}^2}{n_{\rm e}^{\rm n}} \cdot \exp \frac{\Delta E_{\rm F}}{kT}$$

This gives for n<sub>e</sub>n:

$$n_{\rm e}^{\rm n}(U=0) = rac{n_{\rm i}^2}{n_{\rm h}^{\rm p}} \cdot \exp{rac{\Delta E_{\rm F}}{kT}}$$

We now can substitute ne<sup>n</sup> in our <u>first equation</u> and obtain

$$n_{e}^{p} \begin{vmatrix} SCR \\ edge \end{vmatrix} = \frac{n_{i}^{2}}{n_{h}^{p}} \cdot exp \frac{\Delta E_{F}}{kT} \cdot exp - \frac{\Delta E_{F}}{kT}$$
$$\Rightarrow n_{e}^{p} = \frac{n_{i}^{2}}{n_{h}^{p}}$$

That is exactly the second equation – Q.E.D.